TOSHIBA Bi-CMOS Integrated Circuit Silicon Monolithic

## TB6865AFG

## Qi compliant wireless power transmitter IC

## 1. Outline

The TB6865AFG is wireless power transmitter (TX) IC for Qi low power v1.1 compliant of Wireless Power Consortium (WPC). TB6865AFG includes ARM Core Tex M3, PWM control, PreDriver ASK demodulate circuits for wiress power taransfer system.
The IC includes all TX functions needed to construct a standalone wireless power system.

## 2. Applications



LQFP100-P-1414-0.50G

Mobile devices (Smartphone, tablet), Mobile accessory etc.

## 3. Features

- Cortex-M3 manufactured by ARM is used
- RAM : 8Kbyte
- Flash ROM : 128Kbyte
- Pre driver (Drive $4 \times$ Full Bridge circuit) / High Resolution PWM( 100 Hz step): 16 channels
- 12-bit Analog/Digital Converter(ADC) : 14 channels
- ASK signal input : 4 channels
- Input Output ports :64 pins
> Large current for LED drive: 6 pins / Control for buzzer: 1 pin
- General-purpose serial interface(UART) : 2 channels
- Serial bus interface $\left(\mathrm{I}^{2} \mathrm{C}\right.$ bus $) \quad: 1$ channel
- 3.3V LDO
- Fail safe function (Over voltage detection, Over current detection, and Thermal shut down)
- Maximum operation frequency

| CPU | $: 20 \mathrm{MHz}$ |
| :--- | :--- |
| PWM | $: 80 \mathrm{MHz}$ |

- Operating voltage range

Analog and pre driver $: 4.5 \mathrm{~V}$ to 14 V
Digital
: 2.7 V to 3.6 V

- Package
: LQFP100-P-1414-0.50G ( $14 \mathrm{~mm} \times 14 \mathrm{~mm}, 0.5 \mathrm{~mm}$ pitch $)$
About solder ability, following conditions were confirmed
- Solder ability
(1) Use of $\mathrm{Sn}-37 \mathrm{~Pb}$ solder Bath
- solder bath temperature $=230^{\circ} \mathrm{C}$
- dipping time $=5$ seconds
- the number of times = once
- use of R-type flux
(2) Use of $\mathrm{Sn}-3.0 \mathrm{Ag}-0.5 \mathrm{Cu}$ solder Bath
- solder bath temperature $=245^{\circ} \mathrm{C}$
- dipping time $=5$ seconds
- the number of times = once
- use of R-type flux

This product has a MOS structure and is sensitive to electrostatic discharge. When handling this product, ensure that the environment is protected against electrostatic discharge by using an earth strap, a conductive mat and an ionizer. Ensure also that the ambient temperature and relative humidity are maintained at reasonable levels.

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## 4. Block Diagram



Figure 4.1 Block Diagram


Figure 4.2 Block Diagram (CPU Core)

## 5. Pin Assignment



Figure 5.1 Pin Assignment

## 6. Pin Function

Table 6.1 Pin Function

| Pin Number | Pin symbol | I/O | Description | Comment |
| :---: | :---: | :---: | :---: | :---: |
| 1 | VCC2 | - | Power supply pin for CH 5 to CH 8 pre-drivers 2 | (Note 1) |
| 2 | PGND2 | - | Power GND pin for Analog circuit | (Note 2) |
| 3 | NGD2 | 0 | VCC2-4.5V LDO output pin for internal circuit 2 | (Note 3) |
| 4 | VSS | - | Analog GND pin | (Note 2) |
| 5 | FTEST3 | I | TEST pin | (Note 4) |
| 6 | DVDD3 | - | Power supply pin for Digital circuit |  |
| 7 | PF0 | I/O | Input Output Port |  |
| 7 | SDA | I/O | Serial data input output | $\mathrm{I}^{2} \mathrm{C}$ bus(SDA) |
| 8 | PF1 | I/O | Input Output Port |  |
| 8 | $\mathrm{SCL}$ | I/O | Serial clock input output | $\mathrm{I}^{2} \mathrm{C}$ bus(SCL) |
| 9 | PC0 | I/O | Input Output Port |  |
| 9 | TB1OUT | O | TMRB1 Output | Control for Buzzer |
| 10 | PC1 | 1/O | Input Output Port | Large current for LED drive |
| 11 | PC2 | I/O | Input Output Port | Large current for LED drive |
| 12 | PC3 | I/O | Input Output Port | Large current for LED drive |
| 13 | DVSS | - | GND pin | (Note 2) |
| 14 | PC4 | I/O | Input Output Port | Large current for LED drive |
| 15 | PC5 | I/O | Input Output Port | Large current for LED drive |
| 16 | PC6 | I/O | Input Output Port | Large current for LED drive |
| 17 | PAO SWDIO | I/O | Input Output Port |  |
|  |  | I/O | Serial Wire debug port | Debug port |
| 18 | PA1 SWCLK | I/O | Input Output Port |  |
|  |  | I | Serial Wire clock | Debug port |
| 19 | PA2 <br> TRACECLK XBOOT | I/O | Input Output Port |  |
|  |  | 0 | TRACE clock output | Debug port |
|  |  | 1 | Single boot mode |  |
| 20 | PA3 <br> TXD0 <br> TRACEDATA0 SWV | I/O | Input Output Port |  |
|  |  | O | TXD0 |  |
|  |  | 0 | TRACE data output 0 | Debug port |
|  |  | O | Serial Wire Viewer output |  |
| 21 | PA4 <br> RXD0 <br> TRACEDATA1 <br> INT1 | I/O | Input Output Port |  |
|  |  | 1 | RXD0 |  |
|  |  | O | TRACE data output 1 | Debug port |
|  |  | I | External Interrupt 1 |  |

Note 1: When it's not in use, connect to GND.
Note 2: Connect to common ground(GND).
Note 3: It is impossible to supply power to external parts. Connect capacitor ( $0.01 \mu \mathrm{~F}$ ) between NGD2 and VCC2.
Note 4: Must be open.

Table 6.2 Pin Function

| Pin Number | Pin symbol | I/O | Description | Comment |
| :---: | :---: | :---: | :---: | :---: |
| 22 | PA5 <br> TXD1 <br> TRACEDATA2 | 1/O | Input Output Port |  |
|  |  | O | TXD1 | UART(TXD) |
|  |  | O | TRACE data output 2 | Debug port |
| 23 | PA6 <br> RXD1 <br> TRACEDATA3 <br> INTO | 1/O | Input Output Port |  |
|  |  | 1 | RXD1 | UART(RXD) |
|  |  | O | TRACE data output 3 | Debug port |
|  |  | I | External Interrupt 0 |  |
| 24 | RVSS | - | GND pin | (Note 2) |
| 25 | RVDD3 | - | Power supply pin for Regulator |  |
| 26 | AVDD3 | - | Power supply pin for ADC |  |
| 27 | $\begin{aligned} & \text { PDO } \\ & \text { AINO } \end{aligned}$ | 1/O | Input Output Port |  |
|  |  | 1 | ADC input |  |
| 28 | $\begin{aligned} & \text { PD1 } \\ & \text { AIN1 } \end{aligned}$ | 1/O | Input Output Port |  |
|  |  | I | ADC input |  |
| 29 | $\begin{aligned} & \text { PD2 } \\ & \text { AIN2 } \end{aligned}$ | 1/O | Input Output Port |  |
|  |  | I | ADC input |  |
| 30 | $\begin{aligned} & \text { PD3 } \\ & \text { AIN3 } \end{aligned}$ | 1/O | Input Output Port |  |
|  |  | I | ADC input |  |
| 31 | $\begin{aligned} & \text { PD4 } \\ & \text { AIN4 } \end{aligned}$ | 1/O | Input Output Port |  |
|  |  | 1 | ADC input |  |
| 32 | $\begin{aligned} & \text { PD5 } \\ & \text { AIN5 } \end{aligned}$ | 1/O | Input Output Port |  |
|  |  | 1 | ADC input |  |
| 33 | $\begin{aligned} & \text { PD6 } \\ & \text { AIN6 } \end{aligned}$ | 1/O | Input Output Port |  |
|  |  | 1 | ADC input |  |
| 34 | PEO <br> AIN7 | 1/O | Input Output Port |  |
|  |  | 1 | ADC input |  |
| 35 | PE1 <br> AIN8 | I/O | Input Output Port |  |
|  |  | I | ADC input |  |
| 36 | PE2 <br> AIN9 | 1/O | Input Output Port |  |
|  |  | I | ADC input |  |
| 37 | PE3 <br> AIN10 | 1/O | Input Output Port |  |
|  |  | I | ADC input |  |
| 38 | PE4 <br> AIN11 | 1/O | Input Output Port |  |
|  |  | 1 | ADC input |  |
| 39 | PE5 <br> AIN12 | 1/O | Input Output Port |  |
|  |  | 1 | ADC input |  |
| 40 | PE6 <br> AIN13 | 1/O | Input Output Port |  |
|  |  | I | ADC input |  |
| 41 | AVSS | - | GND pin | (Note 2) |
| 42 | VREFH | I | Analog reference input pin for A/D conversion |  |
| 43 | DVDD3 | - | Power supply pin for Digital circuit |  |

Table 6.3 Pin Function

| Pin Number | Pin symbol | I/O |  | Comment |
| :---: | :--- | :---: | :--- | :--- |
|  | XRESET | I | External RESET input | (Note 5) |
| 45 | XT2 | O | Low frequency oscillator output | (Note 6) |
| 46 | XT1 | I | Low frequency oscillator input | (Note 7) |
| 47 | MODE | I | TEST pin | (Note 2) |
| 48 | X2 | O | High frequency oscillator output | (Note 7) |
| 49 | DVSS | - | GND pin |  |
| 50 | X1 | I | High frequency oscillator input |  |
| 51 | PG0 <br> TB5OUT | PG1 <br> TB3OUT | O | TMRB5 Output |

Note 5: Connect with low frequency $X^{\prime}$ tal resonator. If low frequency $X^{\prime}$ 'tal resonator is not connected, XT1 must be pull-up with resistor ( $10 \mathrm{k} \Omega$ ) and XT2 must be open.

Note 6: Must be connected GND.
Note 7: Connect with High frequency X'tal resonator for high accuracy clock.

Table 6.4 Pin Function

| Pin Number | Pin symbol | I/O | Description | Comment |
| :---: | :---: | :---: | :---: | :---: |
| 65 | $\begin{aligned} & \text { PIO } \\ & \text { SCOUT } \end{aligned}$ | 1/O | Input Output Port |  |
|  |  | 0 | Clock output |  |
| 66 | PI1 | 1/O | Input Output Port |  |
| 67 | PI2 | I/O | Input Output Port |  |
| 68 | PI3 | I/O | Input Output Port |  |
| 69 | PI4 | I/O | Input Output Port |  |
| 70 | PI5 | I/O | Input Output Port |  |
| 71 | TEST | 1 | TEST pin (pull-up) | (Note 8) |
| 72 | NGD1 | 0 | VCC1-4.5V LDO output pin for internal circuit 1 | (Note 9) |
| 73 | PVDD | - | System power supply pin |  |
| 74 | VDD33 | I/O | 3.3V LDO Output or Input pin |  |
| 75 | PGND1 | - | GND pin | (Note 2) |
| 76 | VCC1 | - | Power supply pin for CH 1 to CH 4 Pre-drivers 1 | (Note 10) |
| 77 | VIN1 | I | Capture input: Voltage1 |  |
| 78 | VIN2 | 1 | Capture input: Voltage2 |  |
| 79 | VIN3 | I | Capture input: Voltage3 |  |
| 80 | VIN4 | 1 | Capture input: Voltage4 |  |
| 81 | IIN1 | I | Capture input: Current1 |  |
| 82 | IIN2 | 1 | Capture input: Current2 |  |
| 83 | IIN3 | I | Capture input: Current3 |  |
| 84 | IIN4 | 1 | Capture input: Current4 |  |
| 85 | HDRV1 | 0 | High Gate driving force 1 |  |
| 86 | LDRV1 | 0 | Low Gate driving force 1 |  |
| 87 | HDRV2 | 0 | High Gate driving force 2 |  |
| 88 | LDRV2 | 0 | Low Gate driving force 2 |  |
| 89 | HDRV3 | 0 | High Gate driving force 3 |  |
| 90 | LDRV3 | 0 | Low Gate driving force 3 |  |
| 91 | HDRV4 | 0 | High Gate driving force 4 |  |
| 92 | LDRV4 | 0 | Low Gate driving force 4 |  |
| 93 | HDRV5 | 0 | High Gate driving force 5 |  |
| 94 | LDRV5 | 0 | Low Gate driving force 5 |  |
| 95 | HDRV6 | 0 | High Gate driving force 6 |  |
| 96 | LDRV6 | 0 | Low Gate driving force 6 |  |
| 97 | HDRV7 | 0 | High Gate driving force 7 |  |
| 98 | LDRV7 | 0 | Low Gate driving force 7 |  |
| 99 | HDRV8 | 0 | High Gate driving force 8 |  |
| 100 | LDRV8 | 0 | Low Gate driving force 8 |  |

Note 8: Control input/output VDD33. When using external power supply for VDD33, set TEST="L" level.
Note 9: It is impossible to supply power to external parts. Connect capacitor ( $0.01 \mu \mathrm{~F}$ ) between NGD1 and VCC1.
Note 10:When it's not in use, connect to GND.

## 7. Equivalent circuits for input/output/power supply terminals

Table 7.1 Equivalent circuits for power supply terminals

| Pin name | Equivalent circuit |
| :---: | :---: |
| PVDD-VSS,DVSS,RVSS PVDD-PGND1,2 |  |
| VCC1-VSS,DVSS,RVSS <br> VCC2-VSS,DVSS,RVSS <br> VCC1-PGND1,2 <br> VCC2-PGND1,2 |  |
| VSS,DVSS,RVSS-AVSS <br> VSS,DVSS,RVSS-PGND1,2 |  |
| AVDD3-AVSS <br> AVDD3-VSS,DVSS,RVSS |  |
| DVDD3-VSS,DVSS,RVSS RVDD3-VSS,DVSS,RVSS |  |

[^0]Table 7.2 Equivalent circuits of Input / Output terminals
Pin name
PA0
PA2-PA6
PF1 Output Data

Note: Equivalent circuits may be simplified to illustrate circuits.

Table 7.3 Equivalent circuits of Input / Output terminals
Pin name

Note: Equivalent circuits may be simplified to illustrate circuits.

Table 7.4 Equivalent circuits of Input / Output terminals
Pin name

Note: Equivalent circuits may be simplified to illustrate circuits.

Table 7.5 Equivalent circuits of Input terminals
Pin name

Note: Equivalent circuits may be simplified to illustrate circuits.

Table 7.6 Equivalent circuits of Output terminals
Pin name

Note: Equivalent circuits may be simplified to illustrate circuits.

## 8. Function

### 8.1 General outline of wireless power system

Qi compliant wireless power system consists of the first side (TX) which transmits power and the second side (RX) which receives power. Power is transmitted by adjoining coils included in TX and RX and by sharing and combining flux. RX controls the power by monitoring receiving power and sending feedback signal to TX. TX controls the power by controlling transmitting power with feedback signal which is received from RX. Configuration example of wireless power system is shown in Figure 8.1.
Communication signal from RX to TX is transmitted (modulated) by ASK modulation. The communication rate and its packet in this communication are defined by Qi compliant. Communication rate is 2kbps. Packets are ID, identification signal, error information, receive power, and stop signal.TX stops its operation in normal mode. It is powered on intermittently and confirms the existence of RX on the TX pad. When TX recognizes RX and succeeds the identification, transmit operation starts. TX continues transmit operation until TX cannot recognize the existence of RX or receives transmit stop signal from RX.


Figure 8.1 General outline of Wireless power system

### 8.2 Processor Core

The TB6865AFG has a high-performance 32 -bit processor core (the ARM Cortex-M3 processor core). For information on the operations of this processor core, please refer to the "Cortex-M3 Technical Reference Manual" issued by ARM Limited. This chapter describes the functions unique to the TB6865AFG that are not explained in that document.

### 8.2.1 Information on the processor core

The following table shows the revision of the processor core in the TB6865AFG.
Refer to the detailed information about the CPU core and architecture; refer to the ARM manual "Cortex-M series processors" in the following URL: http://infocenter.arm.com/help/index.jsp

| Product Name | Core Revision |
| :---: | :---: |
| TB6865AFG | r2p1 |

### 8.2.2 Configurable Options

The Cortex-M3 core has optional blocks. The following table shows the configurable options in the TB6865AFG.

Table 8.1 Option

| Configurable Options | Implementation |
| :---: | :---: |
| FPB | Two Internal comparators <br> Six Instruction comparators |
| DWT | Four comparators |
| ITM | Implementable |
| MPU | Not implementable |
| ETM | Implementable |
| AHB-AP | Implementable |
| AHB Trace Macro cell Interface | Implementable |
| TPIU | Implementable |
| WIC | Not implementable |
| Debug Port | JTAG / Serial Wire |
| Bit Band | Present |
| Constant AHB control | Absent |

### 8.3 Reset

The TB6865AFG has four reset sources: an external reset pin (XRESET), a low voltage detection reset (LVD) and the setting <SYSRESETREQ> in the Application Interrupt and Reset Control Register.
For reset from the LVD, refer to the 8.10 LVD.
For reset from <SYSRESETREQ>, refer to "Cortex-M3 Technical Reference Manual".

### 8.4 High Resolution PWM Output: (HRPWM)

HRPWM unit consists of four PWM outputs and TB6865AFG has two units of this HRPWM. The functions are as follows.

- Outputs : Eight channels (four channels x two unit)
- Unit1: PWMOUT1/2, PWMOUT3/4, Unit2: PWMOUT5/6, PWMOUT7/8
- It can connect Full Bridge Inverter
- PWM Frequency $: 90 \mathrm{kHz}$ to 205 kHz and 250 kHz
- Frequency step : Under 100 Hz
- Dead time generator : 50 ns to $10 \mu \mathrm{~s}, 50 \mathrm{~ns}$ step


### 8.5 Capture Communication port

Capture Communication Port is use for communication from RX to TX that is defined by Wireless Power Consortium(WPC). (Note)

This IC has four channels of Capture Communication Port. And they can be used independently.

Their features are given in the following.

- Automatic decoding with backscatter modulation signal
- It can be busy to up to ten words

Note: Please refer to WPC document that is "System Description, Wireless Power Transfer, Volume I: Low Power, Part 1: Interface Definition, Version 1.0.3, September 2011".

### 8.6 Pre driver

TB6865AFG has 16 pre-drivers for full-bridge invertor.

### 8.6.1 Configuration



Figure 8.2 Pre-driver circuit

### 8.7 LDO

TB6865AFG has three LDOs. VDD33 is for MCU block and NGD1, NGD2 are for Pre driver. User cannot use these LDOs output since they are only used for inside circuit of this product.

### 8.7.1 VDD33 (Output pin mode)

VDD33 is 3.3 V voltage source for MCU block. Connect capacitor of $1 \mu \mathrm{~F}$ to GND.

### 8.7.2 NGD1,NGD2

NGD1 and NGD2 are LDOs which are used in pre-driver block.
Note: Connect capacitor of $0.01 \mu \mathrm{~F}$ to VCC.

### 8.8 Analog/Digital Converter (ADC)

TB6865AFG contains a 12 -bit, sequential-conversion analog/digital converter (ADC) with 14 analog input channels.

These 14 analog input channels (pins AIN00 through AIN13) are also used as input/output ports.

### 8.9 Power on reset (POR)

The power-on-reset circuit (POR) generates a power-on reset signal when power-on. Power supply voltage is indicated as DVDD3(=AVDD3=RVDD3).

### 8.9.1 Configuration

Power-on-reset circuit consists of the reference voltage generation circuit, comparators, the LVD reset circuit and the power-on counter.

This circuit compares a voltage divided by the ladder resistor with a reference voltage generated in the reference voltage generation circuit in the comparator.


Figure 8.3 Power-on-reset circuit

For details of LVDRCR in LVD reset circuit, refer to Section "Low Voltage Detection Circuit (LVD)".

### 8.10 Low Voltage Detection Circuit (LVD)

Voltage detection circuit generates a reset signal or an interrupt signal (NMI) by detecting a decreasing/increasing voltage.

Supply voltage is indicated as DVDD3(=AVDD3=RVDD3).

Note: Due to the fluctuation of supply voltage, the power-on reset circuit may not operate properly. Users should give due consideration based on the electrical characteristic in the device designing.

### 8.10.1 Configuration

The voltage detection circuit consists of a reference voltage generation circuit, comparators and control registers.

Supply voltage is divided by a ladder resistor and input to the voltage selection circuit. In the voltage selection circuit, a voltage is chosen according to the detected voltage then compared with the reference voltage in the comparator. If the supply voltage is upper/lower than the detected voltage, a reset/interrupt signal occurs.


Figure8.4 Block diagram of LVD (LVD interrupt circuit)

### 8.10.2 Power On and Power Off sequence



Figure8.5 Power on Power off sequence

Note: POR, LVD, Internal RESET are "low" active.

## 9. Absolute Maximum Ratings ( $\mathrm{Ta}=25^{\circ} \mathrm{C}$ )

Table 9.1 Absolute Maximum Ratings

| Characteristics |  | Symbol | Rating | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Supply Voltage |  | DVDD3 | -0.3 to 3.9 | V |
|  |  | AVDD3 |  |  |
|  |  | RVDD3 |  |  |
|  |  | PVDD | -0.3 to 24 | V |
|  |  | VCC1 |  |  |
|  |  | VCC2 |  |  |
| Input Voltage 0 (Note 1) |  | VIN | -0.3 to 3.9 | V |
| Input Voltage 2 (Note 2) |  | VIN2 | -0.3 to min(5.5, PVDD +0.3 ) | V |
| Input Voltage 3 (Note 3) |  | VIN3 | -0.3 to VIN2+0.3 | V |
| Low-level Output Current | Per pin | IoL | 5 | mA |
|  | Total | EloL | 50 |  |
| Low-level Large Output Current | Per pin | lol | 16 |  |
|  | Total | EloL | 50 |  |
| High-level Output Current | Per pin | Іон | -5 |  |
|  | Total | £lOH | -50 |  |
| Output Voltage 1 (Note 4) |  | Vout1 | -0.3 to VCC1 +0.3 | V |
| Output Voltage 2 (Note 5) |  | Vout2 | -0.3 to VCC2 +0.3 | V |
| Output Current (Note 6) |  | Iout1 | 500 | mA |
| Power Consumption <br> (Except during Flash W/E, $\mathrm{Ta}=25^{\circ} \mathrm{C}$ ) |  | PD1 | 2780 | mW |
| Power Consumption <br> (During Flash W/E, $\mathrm{Ta}=25^{\circ} \mathrm{C}$ ) |  | PD2 | 1670 | mW |
| Soldering Temperature (10s) |  | Tsolder | 260 | ${ }^{\circ} \mathrm{C}$ |
| Storage Temperature |  | TSTG | -40 to 125 | ${ }^{\circ} \mathrm{C}$ |
| Operating Temperature | Expect during Flash W/E | Topr | -40 to 85 | ${ }^{\circ} \mathrm{C}$ |
|  | During Flash W/E |  | 0 to 70 |  |

Note: The absolute maximum ratings of a semiconductor device are a set of ratings that must not be exceeded, even for a moment. Do not exceed any of these ratings.
Exceeding the rating (s) may cause the device breakdown, damage or deterioration, and may result injury by explosion or combustion.
Please use the IC within the specified operating ranges.
Note 1: Apply to input terminals except Note 2, 3.
Note 2: Apply to VDD33 terminal (when TEST=0).
$A=\min (A, B)$ when $A \leqq B . B=\min (A, B)$ when $A>B$.
Note 3: Apply to VIN[4:1] and IIN[4:1] terminals.
Note 4: Apply to HDRV[4:1] and LDRV[4:1] terminals.
Note 5: Apply to HDRV[8:5] and LDRV[8:5] terminals.
Note 6: Apply to HDRV[8:1] and LDRV[8:1] terminals.

## 10. DC Electrical Characteristics

### 10.1 DC Electrical Characteristics(MPU part)(1/3)

Table 10.1 DC Electrical Characteristics (MPU part)(1/3)
(Unless otherwise specified, DVSS=AVSS=RVSS=0V, Ta= -40 to $85^{\circ} \mathrm{C}$ )

| Characteristics |  | Symbol | Test condition | Min | Typ. (Note 1) | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply voltage | DVDD3 <br> AVDD3 <br> RVDD3 <br> (Note 2) | $\begin{aligned} & \text { DVDD3 } \\ & \text { AVDD3 } \\ & \text { RVDD3 } \end{aligned}$ | $\begin{aligned} & \text { fosc }=20 \mathrm{MHz} \\ & \text { fsys }=1 \text { to } 20 \mathrm{MHz} \end{aligned}$ | 2.7 | - | 3.6 | V |
| Low-level input voltage |  | VIL1 | $2.7 \mathrm{~V} \leqq \mathrm{DVDD} 3 \leqq 3.6 \mathrm{~V}$ | -0.3 | - | $\begin{aligned} & 0.25 \times \\ & \text { DVDD3 } \end{aligned}$ | V |
| High-level input voltage |  | VIH1 | $2.7 \mathrm{~V} \leqq \mathrm{DVDD} 3 \leqq 3.6 \mathrm{~V}$ | $\begin{aligned} & 0.75 \times \\ & \text { DVDD3 } \end{aligned}$ | - | DVDD3+0.3 | V |
| Low-level output voltage |  | Vol1 | $\begin{aligned} & \mathrm{IOL}=2 \mathrm{~mA} \\ & 2.7 \mathrm{~V} \leqq \mathrm{DVDD} 3 \leqq 3.6 \mathrm{~V} \\ & \text { <Except PC1 to PC6> } \end{aligned}$ | - | - | 0.4 | V |
|  |  | Vol2 | $\begin{aligned} & 1 \mathrm{IO}=10 \mathrm{~mA} \\ & 2.7 \mathrm{~V} \leqq \mathrm{DVDD} 3 \leqq 3.6 \mathrm{~V} \\ & \langle\mathrm{PC} 1 \text { to PC6 }> \end{aligned}$ | - | - | 0.4 | V |
| High-level output voltage |  | VOH | $\begin{aligned} & \mathrm{IOH}=-2 \mathrm{~mA} \\ & 2.7 \mathrm{~V} \leqq \mathrm{DVDD} 3 \leqq 3.6 \mathrm{~V} \end{aligned}$ | 2.4 | - | - | V |
| Input leakage current |  | ILI | $\begin{aligned} & 0.0 \mathrm{~V} \leqq \mathrm{VIN} \leqq \mathrm{DVDD} 3 \\ & 0.0 \mathrm{~V} \leqq \mathrm{VIN} \leqq \mathrm{AVDD3} \end{aligned}$ | - | 0.02 | $\pm 5$ | $\mu \mathrm{A}$ |
| Output leakage current |  | ILO | $\begin{aligned} & 0.2 \mathrm{~V} \leqq \mathrm{VIN} \leq(\text { DVDD3-0.2) } \\ & 0.2 \mathrm{~V} \leqq \mathrm{VIN} \leq(\text { AVDD3-0.2) } \end{aligned}$ | - | 0.05 | $\pm 10$ |  |
| Pull-up resistance (RESET pin) |  | RRST | DVDD3 $=2.7 \mathrm{~V}$ to 3.6 V | - | 50 | 150 | $\mathrm{k} \Omega$ |
| Schmitt triggered port |  | $\mathrm{V}_{\mathrm{TH} 1}$ | $2.7 \mathrm{~V} \leqq \mathrm{DVDD} 3 \leqq 3.6 \mathrm{~V}$ | 0.3 | 0.6 | - | V |
| Programmable pull-up/pull-down resistance |  | PKH | DVDD3=2.7V to 3.6 V | - | 50 | 150 | k $\Omega$ |
| Pin capacitance (except power supply pins) |  | CıO | $\mathrm{fc}=1 \mathrm{MHz}$ | - | - | 10 | pF |

Note 1: Unless otherwise specified, $\mathrm{Ta}=25^{\circ} \mathrm{C}$, DVDD3=RVDD3=AVDD3=3.3 V
Note 2: The same voltage must be supplied to DVDD3, AVDD3 and RVDD3.
Note 3: Ensure that all power supply source is power-off and then power-on again when DVDD3, RVDD3 and AVDD3 falls below 2.7 V which is minimum operating voltage

### 10.2 DC Electrical Characteristics(MPU part) (2/3)

Table 10.2 DC Electrical Characteristics(MPU part) (2/3)

| Characteristics | Symbol | Test condition | Min | Typ. (Note 1) | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Low-level output current | loL1 | $2.7 \mathrm{~V} \leqq \mathrm{DVDD} 3 \leqq 3.6 \mathrm{~V}$ <br> < Except PC1 to PC6> per pin | - | - | 2 | mA |
|  | IOL2 | $2.7 \mathrm{~V} \leqq \mathrm{DVDD} 3 \leqq 3.6 \mathrm{~V}$ <br> <PC1 to PC6> per pin | - | - | 10 | mA |
|  | $\Sigma \mathrm{lOL}$ | Total | - | - | 35 |  |
| High-level output current | IOH | $2.7 \mathrm{~V} \leqq \text { DVDD3 } \leqq 3.6 \mathrm{~V}$ <br> Per pin | - | - | -2.0 | mA |
|  | $\Sigma \mathrm{IOH}$ | Total | - | - | -35 |  |

Note 1: Unless otherwise specified, $\mathrm{Ta}=25^{\circ} \mathrm{C}$, DVDD3=RVDD3=AVDD3 $=3.3 \mathrm{~V}$

### 10.3 DC Electrical Characteristics(MPU part) (3/3)

Table 10.3 DC Electrical Characteristics(MPU part) (3/3)

| Characteristics | Symbol | Test condition | Min | Typ. <br> (Note 1) | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| NORMAL(Note 2) Gear1/1 | IDD | fsys $=20 \mathrm{MHz}$ | - | 15 | 20 | mA |
| IDLE (Note 3) |  |  | - | 7 | 12 |  |
| STOP1 |  | fs $=32.768 \mathrm{kHz}$ | - | 150 | 650 | $\mu \mathrm{A}$ |

Note 1: Unless otherwise specified, $\mathrm{Ta}=25^{\circ} \mathrm{C}$, DVDD3=RVDD3=AVDD3=3.3 V.
Note 2: IDD NORMAL: Measured with Dhrystone ver. 2.1 operated in FLASH. All functions operate excluding A/DC and D/AC.

Note 3: IDD IDLE: Measured with all functions stopped. The currents flow through DVDD3, AVDD3 and RVDD3 are included.

### 10.4 DC Electrical Characteristics(Analog part)

Table 10.4 LDO33
(Unless otherwise specified, $\mathrm{COUT}=1.0 \mu \mathrm{~F}, \mathrm{PVDD}=12 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Characteristics | Symbol | Test condition | Min | Typ. | Max | Unit |
| :--- | :---: | :--- | :---: | :---: | :---: | :---: |
| Supply voltage | PVDD |  | 4.5 | - | 14 | V |
| Output voltage | VDD33 |  | 2.7 | - | 3.6 | V |
| Output current | lout33 |  | - | 60 | - | mA |
| Line regulation | Line33 | PVDD $=5 \mathrm{~V} \rightarrow 14 \mathrm{~V}$ <br> lout33 $=1 \mathrm{~mA}$ | - | - | 33 | mV |
| Load regulation | Load33 | PVDD $=5 \mathrm{~V}$ <br> lout33 $=0 \mathrm{~mA} \rightarrow 60 \mathrm{~mA}$ | - | - | 165 | mV |

Table 10.5 NGD1, NGD2
(Unless otherwise specified, COUT $=0.1 \mu \mathrm{~F}, \mathrm{PVDD}=12 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Characteristics | Symbol | Test condition | Min | Typ. | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply voltage | VCC1 <br> VCC2 |  | 4.5 | - | 14 | V |
|  | NGD1 |  | - | VCC1-4.5 | - |  |
|  | NGD2 |  | - | VCC2-4.5 | - |  |
| Output current | loutNGD1 | NGD1=VCC1-4.5V | - | 15 | - | mA |
|  | loutNGD2 | NGD2=VCC2-4.5V | - | 15 | - |  |

Table 10.6 Pre driver
(Unless otherwise specified, PVDD $=12 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Characteristics | Symbol | Test condition | Min | Typ. | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply voltage | $\begin{aligned} & \text { VCC1 } \\ & \text { VCC2 } \end{aligned}$ |  | 4.5 | - | 14 | V |
| High side MOS Ron | RonH | Ids $=0.1 \mathrm{~A}$ | - | - | 10 | $\Omega$ |
| Low side MOS Ron | RonL | Ids=0.1A | - | - | 10 | $\Omega$ |
| Slew rate rise | Tr | Output capacitor=1000pF | - | - | 100 | ns |
| Slew rate fall | Tf | Output capacitor=1000pF | - | - | 100 | ns |

Table 10.7 Filter
(Unless otherwise specified, PVDD $=12 \mathrm{~V}, \mathrm{Ta}=25^{\circ} \mathrm{C}$ )

| Characteristics | Symbol | Test condition | Min | Typ. | Max | Unit |
| :--- | :---: | :---: | :---: | :---: | :---: | :---: |
| Supply voltage | VDD33 |  | 2.7 | - | 3.6 | V |
| Cutoff frequency (LPF) | FcLPF |  | 2.9 | 5 | 7.5 | kHz |
| Differential input range | Rdiff |  | - | 20 | VDD33 | mV |

### 10.5 12-bit ADC Electric Characteristics

## Table 10.8 12-bit ADC Electric Characteristics

DVDD3=AVDD3=RVDD3=VREFH=2.7V to 3.6V, AVSS=DVSS, Ta $=-40$ to $85^{\circ} \mathrm{C}$
AVDD3 load capacitance $\geqq 3.3 \mu \mathrm{~F}$, VREF load capacitance $\geqq 3.3 \mu \mathrm{~F}$

| Characteristics |  | Symbol | Test condition | Min | Typ. | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Analog reference voltage(+) |  | AVREFH | - | 2.7 | 3.3 | 3.6 | V |
| Analog input voltage |  | $V_{\text {AIN }}$ | - | AVSS | - | VREFH | V |
| Power supply current of analog reference voltage | AD conversion | IREF | DVSS = AVSS | - | 2.0 | 2.5 | mA |
|  | Non-AD conversion |  |  | - | - | 5 | $\mu \mathrm{A}$ |
| Supply current | AD conversion | ADIcc | Except IREF | - | 1.0 | 2.0 | mA |
| INL error |  | - | AIN resistance $\leqq 1 \mathrm{k} \Omega$ <br> AIN load capacitance $\leqq 0.1 \mu \mathrm{~F}$ Conversion time $\geqq 2.0 \mu \mathrm{~s}$ (ADCLK $=20 \mathrm{MHz}$ ) | - | - | $\pm 9$ | LSB |
| DNL error |  |  |  | - | - | $\pm 9$ |  |
| Offset error |  |  |  | - | - | $\pm 9$ |  |
| Full-scale error |  |  |  | - | - | $\pm 9$ |  |
| Total error |  |  |  | - | - | $\pm 9$ |  |
| Conversion time |  | Tconv | ADCLK $=20 \mathrm{MHz}$ | 2 | - | 10 | $\mu \mathrm{s}$ |

Note: 1 LSB $=($ AVREFH - AVSS $) / 4096$ [V]
Note: Peripheral functions are disabled.

```
\pm9LSB@12bit -> \pm2.25LSB@10bit
```


### 10.6 On chip oscillator

Table 10.9 On chip oscillator

| Characteristics | Symbol | Test condition | Min | Typ. | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Oscillating frequency | IHOSC | Ta $=0$ to $85^{\circ} \mathrm{C}$ | - | 20 | - | MHz |

Note: $\pm 3 \%$

### 10.7 Electrostatic Discharge(ESD)

Note: Caution about the electric discharge(ESD) sensitivity of this product.
For ESD test data of this product, please contact your local Toshiba sales representative.
11. Application circuit


## 12. Thermal Estimation

This figure is allowable power dissipation graph of TB6865AFG.


You have to design PCB layout so that power loss does not go beyond this Pd-Ta line in this graph.
This graph is based on JEDEC standard 4 layers PCB. Thermal resistance strongly depends on the size of PCB, the pattern layout, and the number of layer of PCB.

You can thermal calculation with following formulas.

- Using built-in 3.3V LDO.
$\Delta T=\theta j a \times(V p v d d \times I p v d d+V v c c \times I v c c+V p v d d \times I v d d)$

```
Vpvdd =PVDD voltage
lpvdd =PVDD current
Vvcc=VCC1 voltage=VCC2 voltage
lvcc=VCC1 current + VCC2 current
Vvdd=VDD33 voltage=DVDD3 voltage=AVDD3 voltage=RVDD3 voltage
Ivdd33=VDD33 current
Imcu=MCU current
lled= Indicator LED current
Ivdd=Ivdd33+Imcu+lled
```

13. Package Dimensions

LQFP100-P-1414-0.50G



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[^0]:    Note: Equivalent circuits may be simplified to illustrate circuits.

